



Competition of XA and L2₁B ordering in Heusler alloys Mn₂CoZ (Z = Al, Ga, Si, Ge and Sb) and its influence on electronic structure

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ABSTRACT

Competition between the highly-ordered XA structure and disordered L2₁B structure in Heusler alloys Mn₂CoZ (Z = Al, Ga, Si, Ge, Sb) has been investigated. The relative stability of the two structures strongly depends on the main group element Z. When Z belongs to Al or Ga, the XA structure is stabler, but when Z belongs to Si, Ge or Sb, the L2₁B structure gains stability and is lower in energy. This is related to the different number of valence electrons in main group element Z, which influences the DOS structure near the Fermi level and changes N(E_F). The energy difference ΔE between the XA and L2₁B structures may be used to estimate the tendency to form L2₁B structure in different Heusler alloys qualitatively. A large negative ΔE is preferable to retard the A-C site disorder and retain the highly-ordered XA structure. That is just the case in Mn₂CoAl. A robust half-metallicity is observed in Mn₂CoSi, Mn₂CoGe and Mn₂CoSb, they are always half-metallic under either XA or L2₁B structure. But in Mn₂CoAl and Mn₂CoGa, their spin gapless semiconducting character will be destroyed and replaced by a half-metallic state if L2₁B disorder occurs. Finally, these results suggest that the L2₁B structure should be considered together with XA structure when discussing the electronic structure of “inverse” Heusler alloys.

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1. Introduction

In recent years, the Mn₂-based Heusler alloys have attracted much attention for their interesting properties and possible applications in many technical fields. One important application of Mn₂-based Heusler alloys is spintronic materials, till now quite a few Mn₂-based Heusler alloys have been reported to be half-metals or spin gapless semiconductors (SGSs). Some typical examples are Mn₂VAl, Mn₂VSi, Mn₂FeZ (Z = Al, Sb), Mn₂CoZ (Z = Al, Ga, Si, Sb), Mn₂CuSb, Mn₂ZrSi, etc. [1–12]. The half-metallic materials have a 100% spin polarization of the conduction electrons at the Fermi level E_F and are of great importance in spintronics. SGS is an intermediate state between the well known half-metallic ferromagnets and gapless semiconductors. In case of SGS, one spin channel has an open band gap at E_F like a half-metal but the other spin channel has a zero-width gap like a gapless semiconductor [5,13], thus the conducting electrons or holes are not only 100% spin

polarized but also easily excited. Among these Mn₂-based Heusler alloys, Mn₂CoZ (Z = Al, Ga, In, Si, Ge, Sn, Sb) are particularly interesting, for they are not only predicted to be half-metals/SGSs theoretically, but also can be realized experimentally [4,5,14]. It has been found that the unique properties of Mn₂CoZ alloys are strongly related to the preferred occupation of Mn and Co atoms in the cubic lattice of Heusler alloys [15].

Heusler alloys crystallize in a highly-ordered cubic structure and have a stoichiometric composition of X₂YZ, where X and Y are transition metal elements, and Z is a main group element. In Heusler alloys there are four Wyckoff-positions namely A (0, 0, 0), B (0.25, 0.25, 0.25), C (0.5, 0.5, 0.5) and D (0.75, 0.75, 0.75), respectively. The transition metal elements X, Y enter A, B, C sites and main group element Z always enters D sites in the cubic lattice. The site preference of transition metal elements is usually determined by the number of their valence electrons: atoms with more electrons tend to occupy the A and C positions while the atoms with fewer electrons prefer the B position [16]. So in Mn₂CoZ the most possible structure is that one Mn and one Co occupy (A, C) sites and the other Mn enters the B site. In previous literature, people usually assume that Mn and Co occupy the A and C sites respectively [4,17],

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which results in a highly-ordered XA structure (Hg₂CuTi-type, space group No.216), as shown in Fig. 1.

However, a new possible structure named L₂1B may also be considered when discussing the electronic structure and magnetic properties of Heusler alloys Mn₂CoZ. The L₂1B structure evolves from the ordered XA structure [18,19]. In L₂1B type Mn₂CoZ, one Mn and one Co occupy the A and C sites randomly rather than respectively, which results in space group Fm-3m, the same to the L₂1 structure. In Fig. 1, we compared the crystal structures of L₂1B and XA type Mn₂CoAl as an example. In some Fe-based Heusler alloys, the L₂1B structure is found to have a lower total energy compared with XA structure and is stabler [20]. In some Mn₂-based Heusler alloys, the L₂1B structure may increase the total energy slightly, but due to the effect of enthalpy of mixing, it can still be observed in actual samples at room temperature [19]. It has also been found that the L₂1B structure can affect the electronic and magnetic properties of Heusler alloys obviously [21]. Thus it is quite meaningful to investigate the electronic structure and stability of half-metallicity in Heusler alloys under possible L₂1B structure.

In this paper, we investigated the competition between L₂1B and XA ordering in Heusler alloys Mn₂CoZ (Z = Al, Ga, Si, Ge, Sb). A close relation between the phase stability of L₂1B structure and main group element Z has been observed. L₂1B structure is more preferable in several Mn₂CoZ alloys. But the half-metallicity in them is robust under either XA or L₂1B structure.

2. Calculation methods

The electronic structures of Mn₂CoZ (Z = Al, Ga, Si, Ge, Sb) were calculated by using CASTEP code based on pseudopotential method with a plane-wave basis set [22,23]. The interactions between the atomic core and the valence electrons were described by the ultrasoft pseudopotential [24]. The electronic exchange–correlation energy was treated under the generalized-gradient-approximation (GGA) [25]. Supercell approach is used for the calculations of L₂1B structure. The random occupation of Mn and Co at (A, C) sites is treated in a 16-atom supercell, which resulting in a chemical formula of Mn₈Co₄Z₄. The detail can be found in Fig. 1. For all cases, a plane-wave basis set cut-off of 500 eV was used. A mesh of 20 × 20 × 20 or 16 × 16 × 16 *k*-points was employed for Brillouin zone integrations in the XA and L₂1B structures, respectively. These parameters ensured good convergences for total energy. The convergence tolerance for the calculations was selected as a difference on total energy within 1 × 10^{−6} eV/atom.

3. Results and discussions

3.1. Competition between L₂1B and XA ordering in Mn₂CoZ

First, We investigated the site preference of Mn and Co in Mn₂CoZ (Z = Al, Ga, Si, Ge, Sb) and compared the phase stability of XA and L₂1B structures. During structural optimization, we

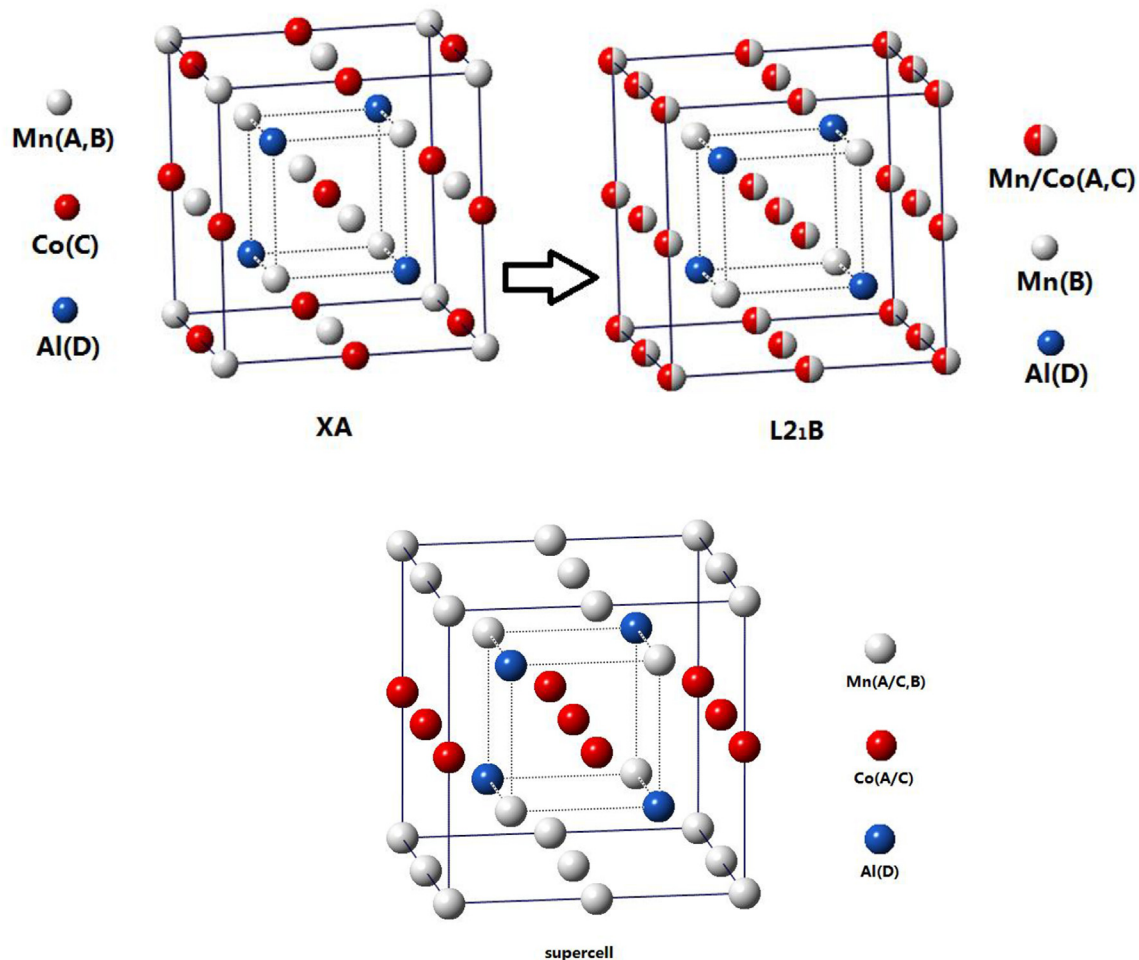


Fig. 1. Crystal structures of XA and L₂1B type Mn₂CoAl, in the L₂1B structure, Mn and Co occupy A, C sites randomly, the L₂1B supercell indicates the exact structure used for calculation, in which Mn and Co atoms occupy four A and four C sites alternately.

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